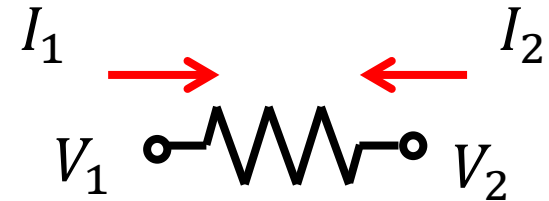

Lecture3: Diode (1)

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Two-terminal element

- Terminal quantities
 - Two terminal voltages
 - Two terminal currents
- Number of independent quantities
 - Note that $I_1 + I_2 = 0$.
 - Note that a common change in V_1 and V_2 does not make a difference.
 - Therefore, I_1 and $V_1 - V_2$ can be regarded as independent variables.
- Each two-terminal element has its own relation between I_1 and $V_1 - V_2$.



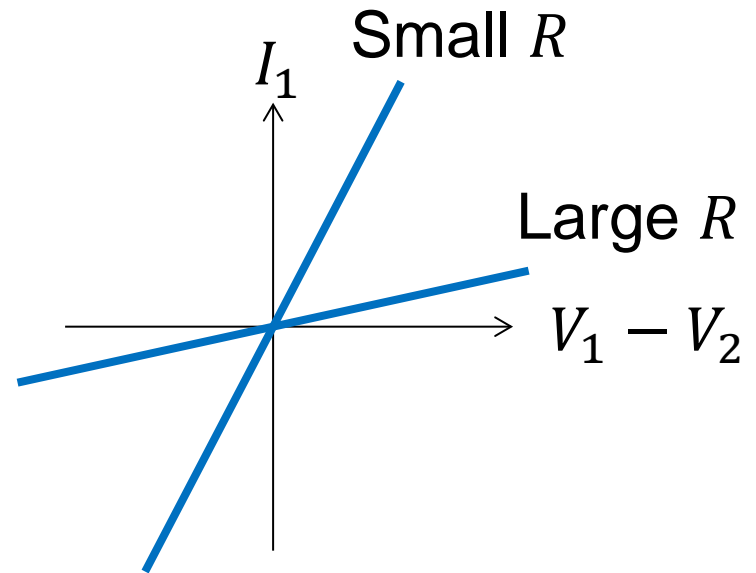
Current vs. voltage

- Sources

- Voltage source: $V_1 - V_2 = \mathbf{V_{source}}$
- Current source: $I_1 = -I_2 = \mathbf{I_{source}}$

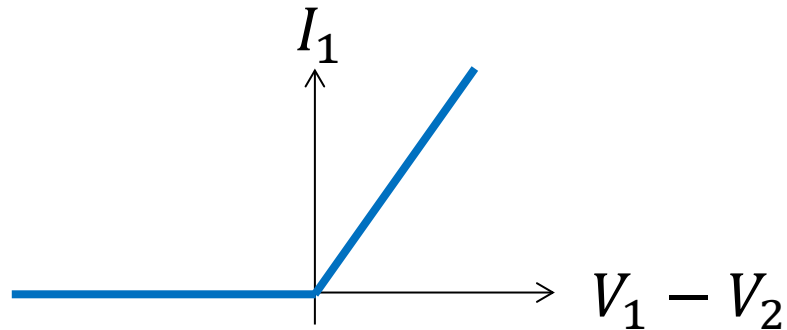
- R, L, C

- Resistor: $I_1 = \frac{V_1 - V_2}{\mathbf{R}}$
- Capacitor: $I_1 = \mathbf{C} \frac{d(V_1 - V_2)}{dt}$
- Inductor: $V_1 - V_2 = \mathbf{L} \frac{dI_1}{dt}$
- They are linear. (When you scale the voltage, the current is scaled with the same factor.)



Nonlinearity?

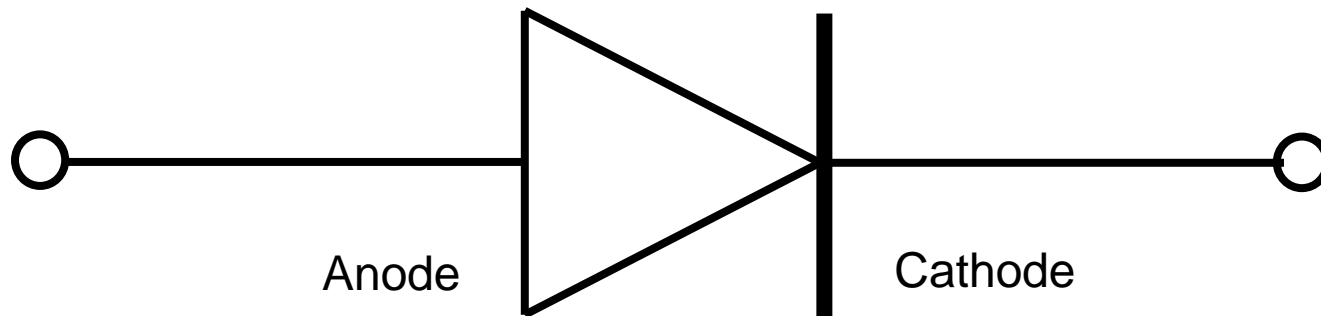
- Consider a toggle light switch.
- Assume a circuit element.



- For a negative voltage, it's electrically open.
- For a positive voltage, it's resistive.
- Is there such a circuit element? Yes!

Diode

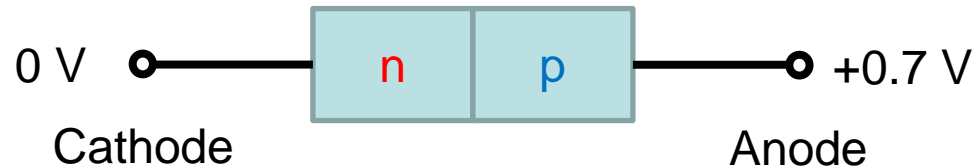
- In 1919, the term *diode* was coined from the Greek roots *di* (from $\delta\acute{\iota}$), meaning 'two', and *ode* (from $\acute{o}\delta\acute{o}\varsigma$), meaning 'path'. (Taken from Wikipedia)
 - Its symbol



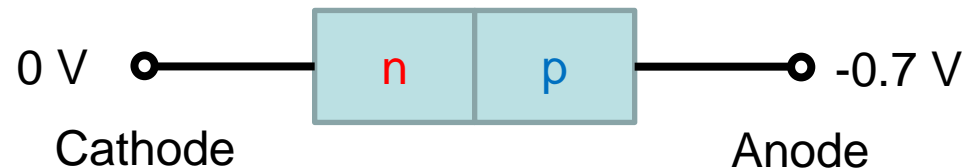
- Current → : Allowed
- Current ← : Not allowed

Forward/reverse

- Forward bias
 - The voltage at the anode is higher than the cathode voltage.

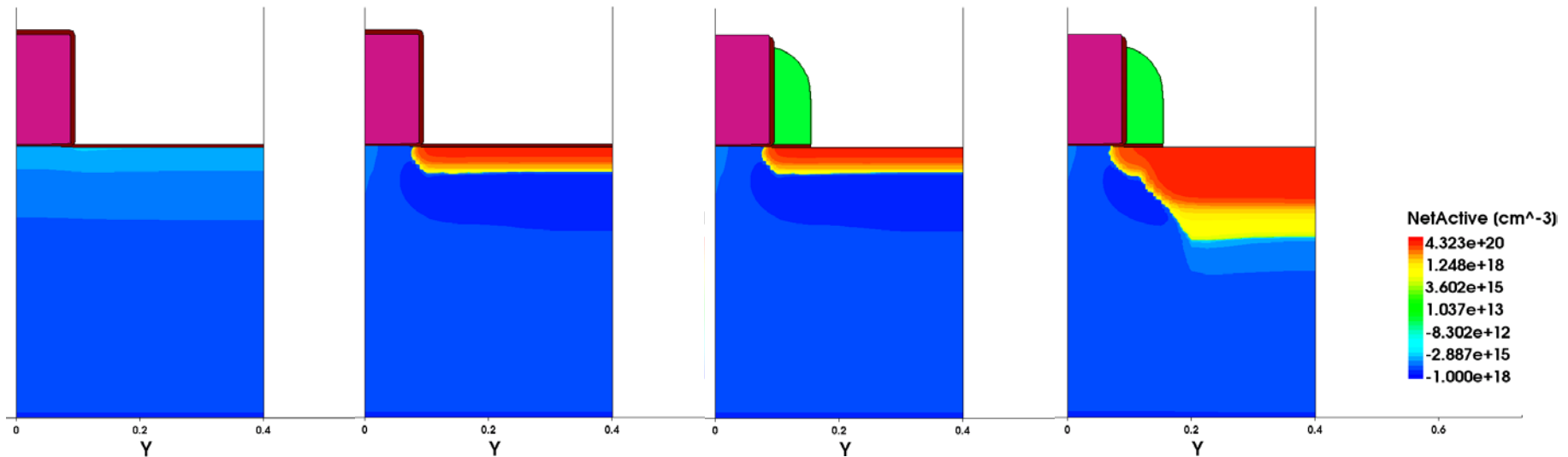


- Reverse bias
 - The voltage at the anode is lower than the cathode voltage.



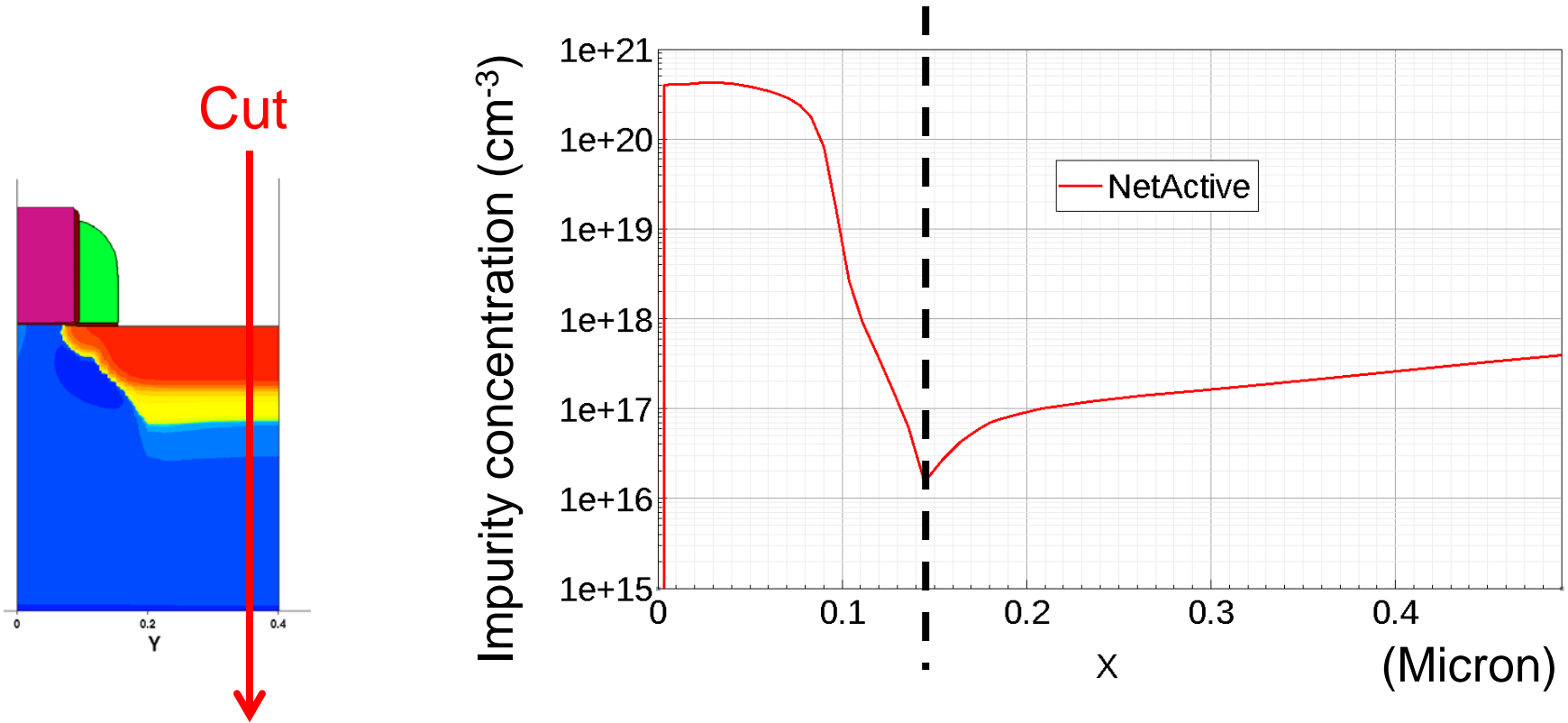
Fabrication

- PN junction
 - Results of the process simulation are shown.
 - Red: Silicon region with Arsenic ions
 - Blue: Silicon region with Boron ions



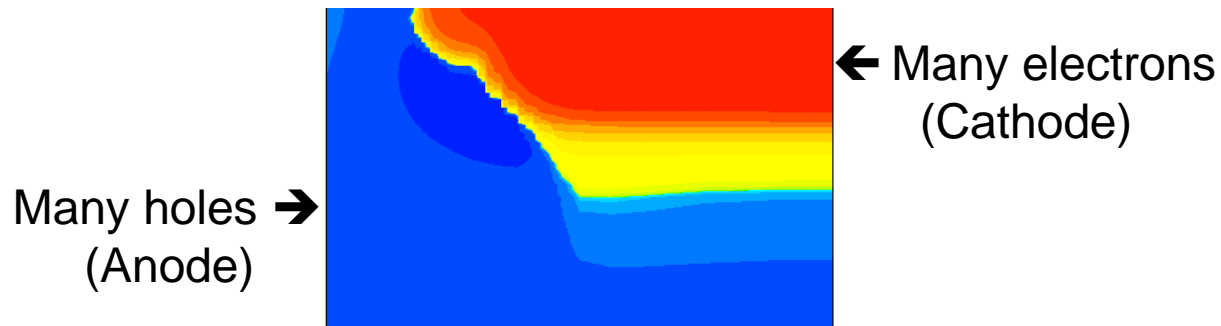
Vertical doping profile

- Active dopant



Equilibrium (1)

- When the applied voltage is zero, no current occurs.
 - Many electrons in the “red” region. (Doped with Arsenic ions. “n-type”)
 - Many holes in the “blue” region. (Doped with Boron ions. “p-type”)
 - Due to the diffusion mechanism, they tend to spread over.
 - Then, we will have the net current! (It’s not possible.)



Equilibrium (2)

- An electric field is built. (Built-in field)
 - It pushes the electrons back to the n-type region.
 - It pushes the holes back to the p-type region.
 - Direction of the electric field?
 - At equilibrium, drift (due to the electric field) and diffusion (due to the density difference) are exactly matched.

